

April 2010

# FAN5340 Synchronous Constant-Current Series Boost LED Driver with PWM Brightness Control and Integrated Load Disconnect

### **Features**

- Synchronous Current-Mode Boost Converter
- Up to 500mW Output Power
- Supports 2, 3, or 4 LEDs in Series
- 2.7V to 4.8V Input Voltage Range
- 1.2MHz Fixed Switching Frequency
- 1mA Maximum Quiescent Current
- Soft-Start Capability
- Input Under-Voltage Lockout (UVLO)
- Output Over-Voltage Protection (OVP)
- Short-Circuit Detection
- Thermal Shutdown (TSD) Protection
- 8-Lead 3.00 x 3.00mm MLP
- 8-Bump 1.57 x 1.57mm WLCSP

# **Applications**

- Cellular Phones, Smart Phones
- Pocket PCs
- WLAN DC-DC Converter Modules
- PDA, DSC, PMP, and MP3 Players

# Description

The FAN5340 is a synchronous constant-current LED driver capable of efficiently delivering up to 500mW to a string of up to four LEDs in series. Optimized for small form-factor applications, the 1.2MHz fixed switching frequency allows the use of chip inductors and capacitors.

For safety, the device features integrated short-circuit detection plus over-voltage and thermal shutdown protections. In addition, input under-voltage lockout protection is triggered if the battery voltage is low.

Brightness (dimming) control is implemented by applying a PWM signal of 300Hz to 1kHz on the EN pin. During shutdown, the FAN5340 disconnects the LED anodes from the output of the boost regulator, which holds the boost regulator's voltage on  $C_{\text{OUT}}$ , reducing audible noise from the PWM dimming and removing power from the LED string.

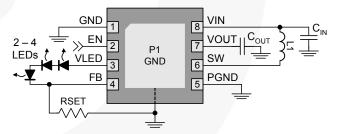


Figure 1. Typical Application

# **Ordering Information**

| Part Number                | Operating<br>Temperature Range | Package  | Packing       |
|----------------------------|--------------------------------|--|---------------|
| FAN5340UCX                 | -40 to 85°C                    | 8-Bump, 1.57 x 1.57mm Wafer Level Chip-Scale Package (WLCSP) | Tape and Reel |
| FAN5340MPX<br>(Prelminary) | -40 to 85°C                    | 8-Lead, 3.00 x 3.00mm Molded Leadless<br>Package (MLP)       | Tape and Reel |

# **Block Diagrams**

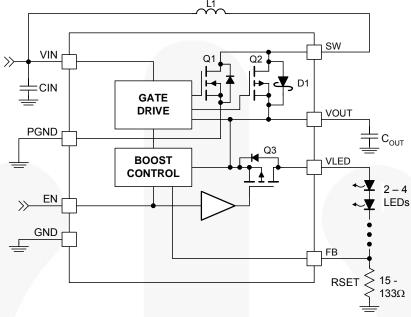


Figure 2. Block Diagram

**Table 1. Recommended External Components** 

| Component       | Description         | Vendor         | Parameter        | Min. | Тур. | Max. | Units |
|-----------------|---------------------|----------------|------------------|------|------|------|-------|
| L1              | 22. II Naminal      | Murata         | L <sup>(1)</sup> |      | 22   |      | μΗ    |
| LI              | 22μH Nominal        | LQH3NPN220MGOK | DCR (Series R)   |      | 1100 |      | mΩ    |
| $C_{OUT}$       | 4.7μF X5R or Better |                | С                |      | 4.7  |      | μF    |
| C <sub>IN</sub> | 4.7μF X5R or Better |                | С                |      | 4.7  |      | μF    |

## Note:

1. Minimum L (inductance) incorporates tolerance, temperature, and DC bias effects (L decreases with increasing current).

# **Pin Configuration**

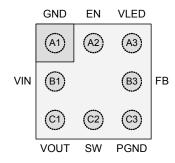


Figure 3. WLCSP Package, Top View

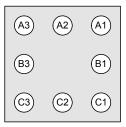


Figure 4. WLCSP Package, Bottom View

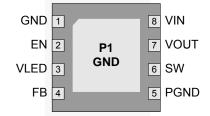


Figure 5. 8-Pin 3 x 3mm MLP, Top View

# **Pin Definitions**

| Pir | า # | Name | Description   |  |  |
|-----|-----|------|---|--|--|
| CSP | MLP | Name | Description   |  |  |
| A1  | 1   | GND  | Analog Ground. All signals are referenced to this pin.  |  |  |
| A2  | 2   | EN   | <b>Enable / PWM Brightness Control</b> . A logic LOW on this pin shuts down the IC, disconnects the LEDs from VOUT, and reduces the current consumption of the IC. This terminal has an internal pull-down resistor of $300k\Omega$ . |  |  |
| A3  | 3   | VLED | LED String Output. Connected to the anode of a series string of two to four LEDs.   |  |  |
| ВЗ  | 4   | FB   | <b>Current Feedback</b> . The boost regulator regulates this pin to 0.5V to control the LED string current. Tie this pin via a current-setting resistor ( $R_{\text{SET}}$ ) to GND and the cathode of the LED string.                |  |  |
| C3  | 5   | PGND | Power Ground. The boost switch and gate drivers are grounded at this pin.   |  |  |
| C2  | 6   | SW   | Switching Node. Tie inductor L1 from V <sub>IN</sub> to this pin.   |  |  |
| C1  | 7   | VOUT | Boost Output Voltage. Output of the boost regulator.  |  |  |
| B1  | 8   | VIN  | Input Voltage.  |  |  |

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol           |                                | Parameter                              |      |                       |    |
|------------------|--------------------------------|--|------|-----------------------|----|
| V <sub>IN</sub>  | VIN                            |  | -0.3 | 6.0                   | V  |
| $V_{FB}, V_{EN}$ | FB, EN Pins                    |  | -0.3 | V <sub>IN</sub> + 0.3 | V  |
| $V_{SW}$         | SW Pin                         |  | -0.3 | 24.0                  | V  |
| V <sub>OUT</sub> | VOUT Pin                       |  | -0.3 | 24.0                  | V  |
| ESD              | Electrostatic Discharge        | Human Body Model per JESD22-A114       | 4.0  |                       | kV |
| ESD              | Protection Level               | Charged Device Model per JESD22-C101   | 1    | .5                    | ΚV |
| TJ               | Junction Temperature           |  | -40  | +150                  | °C |
| T <sub>STG</sub> | Storage Temperature            |  | -65  | +150                  | °C |
| TL               | Lead Soldering Temperature, 10 | Lead Soldering Temperature, 10 Seconds |      | +260                  | °C |

## **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

| Symbol              | Parameter                    | Min. | Тур. | Max. | Units |
|---------------------|------------------------------|------|------|------|-------|
| V <sub>IN</sub>     | VIN Supply Voltage           | 2.7  |      | 4.8  | V     |
| V <sub>OUT</sub>    | VOUT Voltage                 | 6.2  |      | 16.0 | V     |
| I <sub>OUT</sub>    | VOUT Load Current            | 5    |      | 40   | mA    |
| f <sub>EN_PWM</sub> | EN pin PWM Dimming Frequency | 100  | 300  | 1000 | Hz    |
| T <sub>A</sub>      | Ambient Temperature          | -40  |      | +85  | °C    |
| TJ                  | Junction Temperature         | -40  |      | +125 | °C    |

# Thermal Properties

Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with four-layer 2s2p evaluation boards in accordance to JEDEC standard JESD51. Special attention must be paid not to exceed junction temperature  $T_{J(max)}$  at a given ambient temperate  $T_A$ .

| Symbol            | Paramete                               | Parameter     |     |      |
|-------------------|--|---------------|-----|------|
|                   | lunction to Ambient Thomas Decistores  | WLCSP Package | 110 | °C/W |
| $\theta_{\sf JA}$ | Junction-to-Ambient Thermal Resistance | MLP Package   | 49  | °C/W |

# **Electrical Specifications**

 $V_{IN}$  = 2.7V to 4.8V and  $T_A$  = -40°C to +85°C unless otherwise noted. Typical values are at  $T_A$  = 25°C and  $V_{IN}$  = 3.6V.

| Symbol                 | Parameter  | Conditions  | Min. | Тур.                  | Max. | Units |
|------------------------|--|---|------|-----------------------|------|-------|
| Power Sup              | oplies   |   |      |                       |      | •     |
| IQ                     | Quiescent Current                                  | EN = V <sub>IN</sub> , Device Not Switching                             |      |                       | 1    | mA    |
| I <sub>SD</sub>        | Shutdown Supply Current                            | EN = GND, V <sub>IN</sub> = 3.6V  |      | 0.3                   | 1.0  | μΑ    |
| \/                     | Linder Voltage Leekeut                             | V <sub>IN</sub> Rising  | 2.30 | 2.40                  | 2.50 | V     |
| $V_{\text{UVLO}}$      | Under-Voltage Lockout                              | V <sub>IN</sub> Falling   | 2.00 | 2.15                  | 2.25 | V     |
| V <sub>UVHYST</sub>    | Under-Voltage Lockout Hysteresis                   |   |      | 250                   |      | mV    |
| EN: Enabl              | e Pin  |   |      |                       |      |       |
| $V_{IH}$               | HIGH-Level Input Voltage                           |   | 1.2  |                       |      | V     |
| $V_{IL}$               | LOW-Level Input Voltage                            |   |      |                       | 0.4  | V     |
| $R_{EN}$               | EN Pull-Down Resistance                            |   | 200  | 300                   | 400  | kΩ    |
| t <sub>SD</sub>        | EN Low to Shutdown Delay                           | From Falling Edge of EN   | 20   |                       | 80   | ms    |
| Feedback               | and Reference                                      |   |      |                       |      |       |
| $V_{FB}$               | Feedback Voltage                                   |   | 480  | 500                   | 520  | mV    |
| I <sub>FB</sub>        | Feedback Input Current                             | V <sub>FB</sub> = 500mV   |      | 0.1                   | 1.0  | μΑ    |
| Power Ou               | tputs  |   |      |                       |      |       |
| В                      | Boost Switch On-Resistance                         | V <sub>IN</sub> = 3.6V, V <sub>OUT</sub> = 10V, I <sub>SW</sub> = 100mA |      | 600                   |      |       |
| R <sub>DS(ON)_Q1</sub> |  | V <sub>IN</sub> = 2.7V, V <sub>OUT</sub> = 10V, I <sub>SW</sub> = 100mA |      | 850                   |      | mΩ    |
| R <sub>DS(ON)_Q2</sub> | Synchronous Rectifier On-Resistance                | V <sub>OUT</sub> = 10V, I <sub>SW</sub> = 100mA                         |      | 2.0                   |      | Ω     |
| R <sub>DS(ON)_Q3</sub> | Load Switch On-Resistance                          | V <sub>OUT</sub> = 10V, I <sub>LED</sub> = 10mA                         |      | 2.8                   |      | Ω     |
| I <sub>SW(OFF)</sub>   | SW Node Leakage <sup>(2)</sup>                     | $EN = 0$ , $V_{IN} = V_{SW} = V_{OUT} = 5.5V$ , $V_{LED} = 0$           |      | 0.1                   | 1.0  | μА    |
| I <sub>LIM-PK</sub>    | Boost Switch Peak Current Limit                    | V <sub>IN</sub> = 3.6V  | 325  | 400                   | 475  | mA    |
| Oscillator             |  |   |      | -1                    |      |       |
| f <sub>SW</sub>        | Boost Regulator Switching Frequency                |   | 1.0  | 1.2                   | 1.4  | MHz   |
| PWM Dim                | ming   |   |      | -                     |      | •     |
| D <sub>PWM</sub>       | PWM Duty Cycle <sup>(3)</sup>                      | PWM Dimming Frequency ≤1kHz   | 1.0  |                       | 100  | %     |
| Output an              | d Protection                                       |   |      |                       |      |       |
| V <sub>OVP</sub>       | Boost Output Over-Voltage Protection               |   | 18.0 | 19.0                  | 20.0 | V     |
| V <sub>OVPHYST</sub>   | OVP Hysteresis                                     |   |      | 0.8                   |      | V     |
| \/                     | V Chart Circuit Detection Thereby                  | V <sub>OUT</sub> Falling  |      | V <sub>IN</sub> - 1.5 |      | V     |
| $V_{THSC}$             | V <sub>LED</sub> Short-Circuit Detection Threshold | V <sub>OUT</sub> Rising   |      | V <sub>IN</sub> - 1.3 |      | V     |
| D <sub>MAX</sub>       | Maximum Boost Duty Cycle <sup>(3)</sup>            |   | 85   |                       |      | %     |
| D <sub>MIN</sub>       | Minimum Boost Duty Cycle <sup>(3)</sup>            |   |      |                       | 20   | %     |
| T <sub>SD</sub>        | Thermal Shutdown                                   |   |      | 150                   | /1 / | °C    |
| T <sub>HYS</sub>       | Thermal Shutdown Hysteresis                        |   |      | 25                    |      | °C    |

## Notes:

- 2. SW leakage current includes the leakage current of three internal switches; SW to GND, V<sub>OUT</sub> to V<sub>LED</sub>, and SW to V<sub>OUT</sub>.
- 3. Guaranteed by design.

## **Typical Characteristics**

 $V_{IN}$  = 3.6V,  $T_A$  = 25°C,  $I_{LED}$  = 20mA, L = 22 $\mu$ H,  $C_{OUT}$  = 4.7 $\mu$ F.

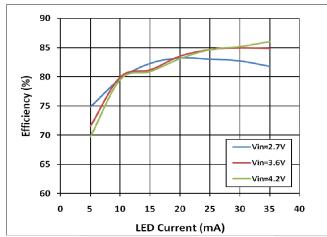


Figure 6. Efficiency vs. LED Current: Two LEDs

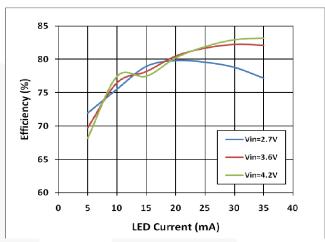


Figure 7. Efficiency vs. LED Current: Three LEDs

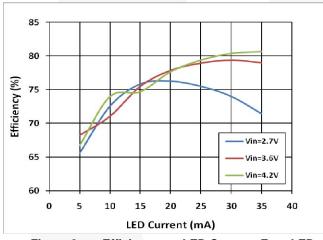


Figure 8. Efficiency vs. LED Current: Four LEDs

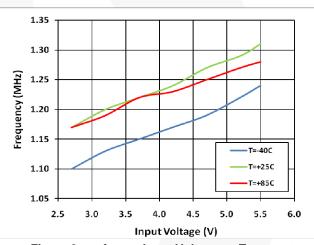


Figure 9. f<sub>SW</sub> vs. Input Voltage vs.Temperature

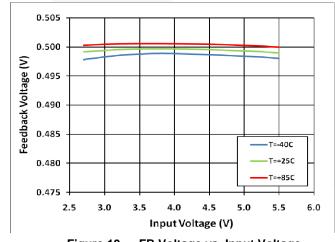


Figure 10. FB Voltage vs. Input Voltage vs. Temperature

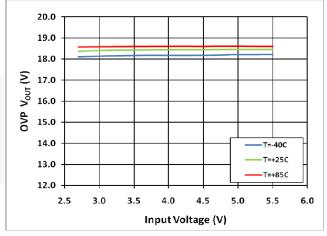
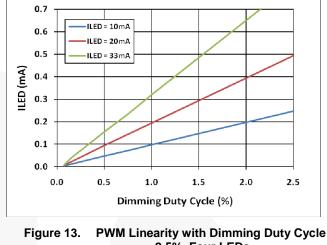


Figure 11. OVP vs. Input Voltage vs. Temperature

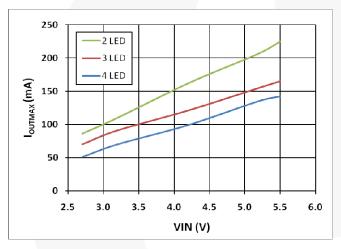
# **Typical Characteristics** (Continued)



Figure 12. **PWM Linearity Over Full Dimming Duty** Cycle Range, Four LEDs



<2.5%, Four LEDs



Maximum Output Current at Vout

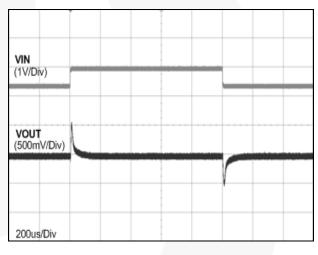
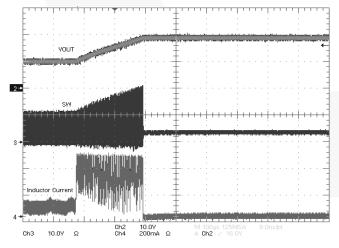


Figure 15. Line Transient with 10µs Line Step, **Four LEDs** 



Over-Voltage Protection: Soft-Start into Figure 16. **Open LED String** 

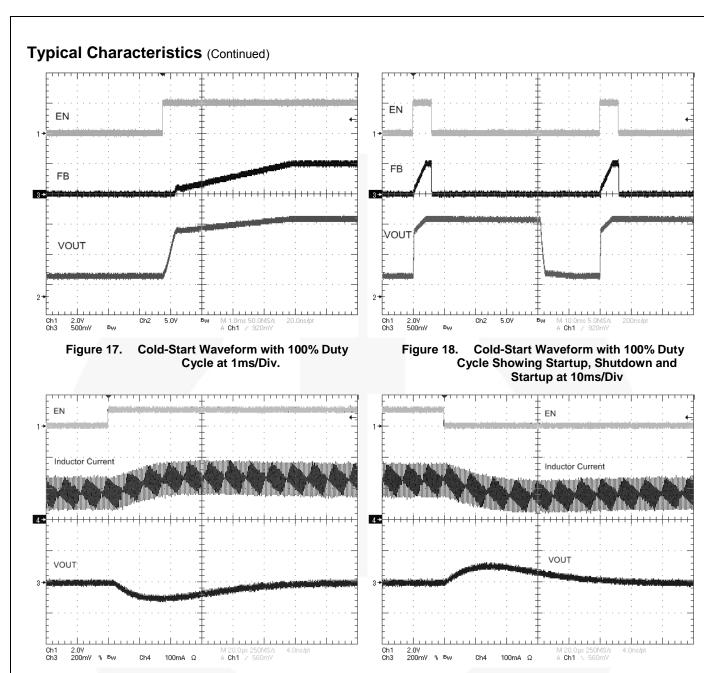


Figure 19. FAN5340 I<sub>LOAD</sub> Step from 20mA to 30mA by Enabling FAN5640 at 10mA, Three LEDs

Figure 20. FAN5340 I<sub>LOAD</sub> Step from 30mA to 20mA by Disabling FAN5640 at 10mA, Three LEDs

## **Circuit Description**

#### Overview

The FAN5340 is an inductive current-mode boost serial LED driver that achieves LED current regulation by maintaining 0.5V across  $R_{\text{SET}}$ . The current through the LED string ( $I_{\text{LED}}$ ) is therefore:

$$I_{LED} = \frac{0.5}{R_{SET}} \tag{1}$$

While the forward-voltage across the LEDs determines  $V_{\text{OUT}}$ , the FAN5340's boost regulator output can also support additional loads on  $V_{\text{OUT}}$  (see Figure 21) provided its input current limit is not exceeded.

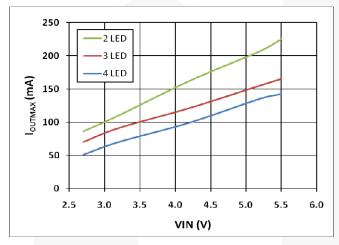


Figure 21. Maximum Output Current vs. Input Voltage

#### **UVLO and Soft-Start**

If EN has been LOW for more than 20ms, the IC initiates a "cold start" soft-start cycle when EN rises, provided  $V_{\text{IN}}$  is above the UVLO threshold. The soft-start circuit ramps the voltage reference to the error amplifier to control inrush current.

## **PWM Dimming**

When EN goes LOW, the IC turns off a MOSFET (Q3 in Figure 2), which disconnects the LED load, preventing  $C_{\text{OUT}}$  from being discharged when EN is LOW. As long as EN is low for less than 20ms, the regulator's main regulation loop quickly regains control when EN returns to a HIGH state.

### **Short-Circuit Detection**

If  $V_{OUT}$  falls below  $V_{IN}-1.5V,\ Q3$  turns off and remains off until  $V_{OUT}$  recovers to at least  $V_{IN}-1.3V.$ 

## **Over-Voltage Protection**

If the LED string is open circuit, FB remains at 0V and the output voltage continues to increase in the absence of an Over-Voltage Protection (OVP) circuit. The FAN5340's OVP circuit disables the boost regulator when  $V_{\text{OUT}}$  exceeds 19.0V and continues to keep the regulator off until  $V_{\text{OUT}}$  drops below 18.2V.

#### Thermal Shutdown

If the die temperature exceeds 150°C, a reset occurs and remains in effect until the die cools to 125°C, at which time the circuit is allowed to begin the soft-start sequence.

## **Applications**

## **Using VOUT to Drive Additional LED Strings**

The VOUT pin can be used as a supply for simple current sources (shown in Figure 22 using the FAN5640) or discrete current sinks. To avoid dragging  $V_{\text{OUT}}$  down when the EN pin is LOW, the auxiliary strings should not be enabled unless the EN pin is HIGH. The auxiliary strings can therefore be PWM dimmed using either the same line as the EN line as shown below or enabled separately, but within the on-time of the FAN5340.

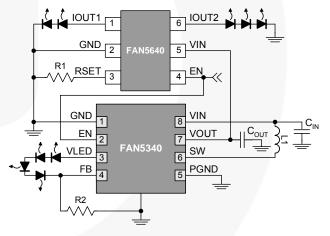
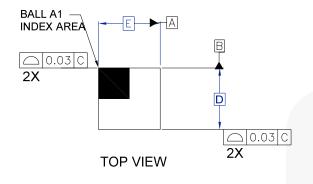
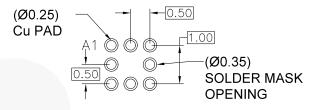


Figure 22. Driving Additional LED Strings

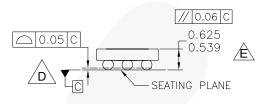
If using VOUT to drive additional loads, care should be taken not to exceed the input current limit. This limitation is shown in Figure 21 for a typical IC. The total load ( $I_{\rm OUT}1 + I_{\rm OUT}2 + I_{\rm LED}$ ) should always remain below 70% of the value in Figure 21.

## **Physical Dimensions**





RECOMMENDED LAND PATTERN (NSMD)





SIDE VIEWS

#### NOTES:

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C, DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994
- DATUM C, THE SEATING PLANE, IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- E. PACKAGE TYPICAL HEIGHT IS 582 MICRONS ± 43 MICRONS (539-625 MICRONS).



- G. BALL COMPOSITION: Sn95.5-Ag3.9-Cu0.6
- I. DRAWING FILENAME: MKT-UC008ABrev2.

# 

## **Product-Specific Dimensions**

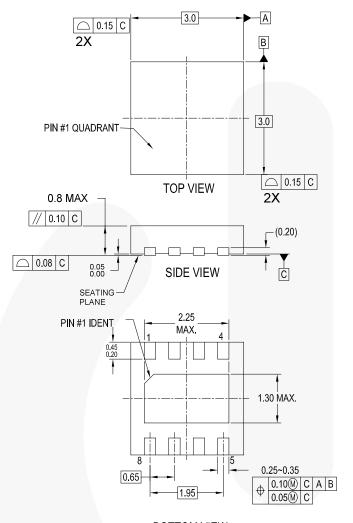
| Product   | D     | E     | X     | Υ     |
|-----------|-------|-------|-------|-------|
| FAN5340UC | 1.570 | 1.570 | 0.285 | 0.285 |

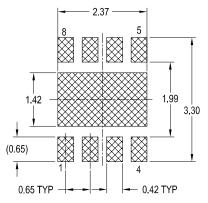
Figure 23. 8-Bump, 1.57 x 1.57mm Wafer Level Chip-Scale Package (WLCSP)

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## Physical Dimensions (Continued)





RECOMMENDED LAND PATTERN

NOTES: BOTTOM VIEW

A. CONFORMS TO JEDEC REGISTRATION MO-229, VARIATION VEEC, DATED 11/2001

- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994
- D. FILENAME: MKT-MLP08Drev2

Figure 24. 8-Pin, 3 x 3mm Molded Leadless Package (MLP)

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IntelliMAXTM
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MicroFETTM
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SuperFETTM
SuperSOTTM-8
SuperSOTTM-8
SuperSOTTM-8
SuperSOTTM-8
SuperSOTTM-8
SuperMOSTM
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|---|-----------------------|---|--|--|
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| Preliminary   | First Production      | Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design. |  |  |
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